

HEAT CAPACITY OF LIQUID ALLOYS

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Introduction

Of all the thermodynamic properties of liquid alloys heat capacity has been by far the most neglected quantity, and even for pure liquid metals accurate data are known only for a relatively small number of low melting elements. Since it has been recognized some time ago (1) that valuable information as to the atomic arrangements is contained in the heat capacities of liquid alloys, a review of the present state might be appropriate to stimulate interest.

Liquid metals

The values of C_p for most liquid main group metals including Cu, Ag, Au and Zn, Cd, Hg near the melting point cluster around $30 \text{ J K}^{-1} \text{ mol}^{-1}$, i.e. close to $3R$ for the vibrational contribution to the heat capacity of the solid plus the dilatation contribution $C_d = C_p - C_v = \alpha^2 V T / \kappa_T$ where α is the coefficient of thermal expansion and κ_T the isothermal compressibility (2). Any deviations are considered to be caused either by the anharmonicity of atomic vibrations or by electronic contributions. Especially for the high melting transition metals Margrave (3) has pointed out that deviations are mostly due to the electronic terms, and that the actual density of states at high temperatures should be taken into account and not the low temperature term $C_{el} = \gamma T$. Accurate data of some low melting metals show that C_p in the liquid state first decreases with increasing temperature, passes through a minimum, and then increases again. At very high temperatures (2000-5000 K) C_p of liquid transition metals may reach values of 8 to 10 R (4). Chapman (2) has developed a general theory for the heat capacity of monoatomic fluids, based on the radial distribution function. By applying the corresponding states principle he could show that C_v of the liquid metals investigated (Na, K, Hg, In, Sn, Pb) was a universal function of only two dimensionless parameters and decreased steadily with increasing temperature. The upturn in C_p is therefore caused by the dilatation term. With reasonable assumptions for the distance and energy parameters Chapman obtained a single curve for the reduced configurational heat capacity and concluded that the configurational heat capacities of these liquid metals obey a corresponding states law and that the decrease of C_v with temperature can be explained by the effect of temperature on the liquid structure. According to Kincaid and Eyring (5) the decrease is caused by a gradual destruction of vibrational contributions as the liquid approaches increasingly a monoatomic gas. Close to the critical temperature $C_v - C_{el}$ for Na, K, and Hg approaches $2R$ which is explained by the gradual loss of excitations corresponding to the two shear modes (6). Hoch and Vernardakis (7) showed that the heat capacities of liquid Li, K, Na, Pb and Hg can be expressed as $C_p = 3RF(\Theta_D/T) + gT + hT^{-2}$ where $F(\Theta_D/T)$ is the Debye function, g the electronic heat capacity term, and h the anharmonic term which according to Faber (8) may be due to some crystallites or complexes in the liquid. The vibration of the atoms in the complexes would be quite anharmonic but with increasing temperature complexes and therefore anharmonicity of the liquid would disappear, and when the temperature is high enough

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a gas-like liquid would result. However, other thermophysical properties did not support the existence of clusters in these liquid metals (7).

Not all liquid metals obey Chapman's relationship (2) as was demonstrated for liquid Ga (9) and liquid Te (10). An application of the hard-sphere model to C_p of liquid Ga (9) also showed that it cannot be fully accounted for in terms of the simple hard-sphere approximations. In the case of liquid Te C_p decreases from $49.32 \text{ J K}^{-1} \text{ mol}^{-1}$ at 740 K to $33.47 \text{ J K}^{-1} \text{ mol}^{-1}$ at 1073 K . This behaviour was explained by an equilibrium between semiconducting and metallic regions in the liquid shifting towards the metallic state with increasing temperature using the effective medium percolation theory by Cohen and Jortner (11-13). The heat capacity of liquid Se on the other hand is $35.95 \text{ J K}^{-1} \text{ mol}^{-1}$ at the melting point (494.33 K), passes through a shallow minimum at 780 K ($33.28 \text{ J K}^{-1} \text{ mol}^{-1}$) and increases to $35.62 \text{ J K}^{-1} \text{ mol}^{-1}$ at 1000 K (14).

Liquid alloys

The heat capacity of liquid alloys will generally also decrease with increasing temperature but in most cases data are lacking and a constant temperature-independent value calculated from the Neumann-Kopp rule of additivity is assumed. One of the early direct measurements of C_p of a liquid alloy was that of Orr et al. (15) of an In-Sn alloy. They observed a marked decrease of C_p with increasing temperature which according to them could be interpreted as resulting from two possible causes : 1) a decrease in interactions of non-random associations between unlike atoms resulting in ΔC_p positive ; 2) changes in structure or in the vibrational and translational energy distributions such as those postulated for pure metals giving $\Delta C_p \approx 0$ as was observed for the liquid In-Sn alloy (15). Therefore the quantity directly indicative of interactions or associations in a liquid alloy will be ΔC_p and not C_p , and one would expect ΔC_p either to be nearly zero or positive. This is indeed observed in most binary alloys. Only in a few systems with a positive enthalpy of mixing and a strongly positive excess entropy of mixing (Cd-Sn, Sn-Zn) Kleppa (16) found ΔC_p negative, and a correlation between ΔS_{mix} ,_{xs} and ΔC_p , and ΔS_{mix} ,_{xs} and the volume expansion on mixing ($\Delta V_{\text{vol}} \approx \Delta V_a/k_T$). Chen and Turnbull (17) found a positive ΔC_p decreasing with temperature for a liquid Au-Si alloy near the eutectic composition. As an explanation they suggested three possible causes : 1) a change in the vibrational spectrum due to a change in the type of bonding during melting ; 2) a decrease in non-random association between unlike atoms with increasing temperature ; 3) changes in configurational entropy from the multiplicity of atomic positioning. They concluded that the change in structural configurational entropy with temperature makes a major contribution to ΔC_p .

In 1967 Hultgren and Orr (1) remarked that the only direct C_p measurements for liquid alloys known to them were on one alloy each in the Bi-In and In-Sn system. Even today direct C_p measurements especially for an entire binary system are very scarce, and most information albeit sometimes of questionable reliability has to be drawn indirectly from ΔH^{M} measurements.

A search of the literature has resulted in 78 binary alloy systems for which some information about ΔC_p is known. These systems are listed in Table 1 together with ΔC_p , the temperature range, and the enthalpy of mixing, ΔH^{M} . Appended to Table 1 are the references to the systems listed in the table. Most of the systems are binaries between main group elements including elements of Group IB and IIB of the PSE. The reason is purely experimental : due to lower liquidus temperatures they are more easily accessible. Only seven systems have another transition element as component (Ce-Cu, Cu-Te, Cu-Ti, Ge-Pt, Pd-Si, Pd-Sn, Ni-Sn) of which two systems have two transition elements as components (Ce-Cu, Cu-Ti). Of the 79 systems 62 have a positive ΔC_p , 13 $\Delta C_p = 0$, and four a negative ΔC_p . All but two (Bi-Ga, Ga-Hg) of the 62 systems with positive ΔC_p have (at least over a limited concentration range) a negative enthalpy of mixing. For Bi-Ga ΔC_p is very small and was obtained indirectly from the temperature dependence of ΔH^{M} . In Ga-Hg C_p was measured directly and very precisely by a pulse modulation technique for the critical composition just above the liquid miscibility gap ; ΔC_p could not be calculated since the heat capacity of alloy plus container was measured but from the plot of C_p vs. temperature it is clear that ΔC_p is positive at the critical temperature decreasing to zero about 5 K.

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Table 1. Relative Heat Capacity and Enthalpy of Mixing of Liquid Alloys

System	$\Delta C_p(T; x_1)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_1)$ (J mol ⁻¹)	Ref.	Remarks
Ag-Al	22.5*(1100; 0.7)	1073-1123	1)	-8700*(1073; 0.7)	2)	ΔC_p indir., const.; ΔH^M pos. & neg., by two different groups.
Ag-Ga	3.84(900; 0.55)	773-1028	2)	-4810*(1028; 0.75)	2)	ΔC_p indir., const.; ΔH^M pos. & neg.
Ag-Ge	25.80(930; 0.74)	930-1200	3)	-795*(1280; 0.90)	4)	C_p direct, for one comp.; ΔC_p decr. with T; $\Delta C_p = -0.6$ (1000 K); ΔH^M pos. & neg.
Ag-In	1.17(1000; 0.3)	743-1280	5)	-4800*(1280; 0.60)	5)	ΔC_p indir., const.
Ag-Sb	11.1*(1100; 0.8)	950-1300	4)	-7950*(950; 0.8)	4)	ΔC_p indir., const.; ΔH^M pos. & neg.
Ag-Sn	pos.	-	4)	-3210*(1280; 0.8)	4)	ΔC_p indir.; ΔH^M pos. & neg.
Ag-Te	0	1165-1578	6)	-20750*(1165; 0.667)	6)	ΔH^M const.
Al-Bi	0	940-1077	7)	+42000*(1077; 0.5)	7)	ΔH^M const., misc. gap, ΔH^M max. interpolated
Al-Ca	~50(973; 0.67) 21(1000; 0.92)	953-1038	8) 9)	-39230*(1038; 0.67)	9)	$\Delta C_p \approx 20$ (11200; 0.80) indir. ΔC_p indir., const.; ΔH^M for Al(1) + Ca(s) \rightarrow Al ₂ Ca(s)
Al-Cu	4.28(1200; 0.5)	1073-1423	2)	-19150*(1073; 0.45)	2)	ΔC_p indir., const.; ΔH^M by two different groups.
Al-Ga	0	952-1235	10)	+660*(952; 0.50)	10)	ΔH^M const.
Al-Te	pos.	1000-1188	11)	-64000*(1188; 0.40)	12)	$\Delta \overline{C}_p^{\infty}(T) = 63 \pm 10$, indir.
As-Cd	45.6*(1000; 0.45)	983-1013	13)	-7020*(983; 0.45)	13)	ΔC_p indir., pos. and neg.; ΔH^M pos. & neg.
As-Sn	pos.	870-1100	14)	-	-	C_p by drop cal.; C_p first decr., then incr. with T.
Au-Cd	pos.	773-873	15)	-17200*(1000; 0.5)	16)	$\Delta \overline{C}_p(Cd)$ indir., pos., 10.2 (825; 0.30)
Au-Cs	10.26*(1040; 0.5)	900-1180	17)	-41510*(900; 0.5)	17)	ΔC_p indir., const.

System	$\Delta C_p(T; x_i)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_i)$ (J mol ⁻¹)	Ref.	Remarks
Au-Ga	11.71 ^x (925; >0.8)	823-1028	2)	-18200 ^x (830; 0.60)	18)	ΔC_p indir., const.; second max 8.05 (925; 0.55)
	8.85 ^x (800; 0.33)	765-873	19)	-	-	C_p dir., const.; ΔC_p = 7.00 (800; 0.5)
Au-Ge	4.0(630; 0.72)	630-990	20)	-5900 ^x (1223; 0.65)	2)	C_p dir., for one comp.; ΔC_p decr. with T
Au-In	4.93 ^x (900; 0.55)	823-1028	2)	-18625 ^x (823; 0.60)	2)	ΔC_p indir., const.
	8.67 ^x (800; 0.60)	720-1300	21)	-17880 ^x (823; 0.55)	22)	ΔC_p indir., decr. with T; second max. (800; >0.8)
	7.90(850; 0.33)	817-873	19)	-	-	C_p dir., const.; ΔC_p = 6.27 (830; 0.5)
	6.07 ^x (800; 0.45)	800-920	87)	-	-	C_p by DSC, sec. max. (800; >0.7) ΔC_p decr. with T.
Au-Pb	3.85 ^x (875; 0.55)	823-923	2)	-20000 ^x (823; 0.60)	2)	ΔC_p indir., const; ΔH^M possibly neg & pos. (22)
Au-Sb	5.49(800; 0.33)	733-873	19)	-3200 ^x (923; 0.75)	2)	C_p dir. const.
Au-Si	18.8(625; 0.80 _y)	625-1350	23)	-	-	C_p by drop cal. for one comp. ΔC_p decr. with T to -5.6 (1350 K)
	5.7 ^x (1000; 0.50)	1373-2000	24)	-7620 ^x (1373; 0.70)	24)	ΔC_p indir., const.; calorimetry at 1373 K; mass spectrometry 1550-2000 K.
	8.97(563; 0.814)	563-800	25)	-	-	C_p by DSC, ΔC_p decr. with T to 7.82 (636 K)
	8.75 ^x (700; 0.50)	700-1500	26)	-12620 ^x (707; 0.55)	26)	ΔC_p indir., second max. >9.16 (700; >0.80) ΔC_p decr. with T to -2.87 (1500; >0.5)
Au-Sn	pos., then neg.	1100-1873	27)	-15400 ^x (1873; 0.5)	27)	ΔC_p first pos. (up to 1100 K) then neg. (up to 1873 K), by comp. with literat.
	6.12(780; 0.50)	691-873	19)	-	-	C_p dir. const.
	5.5 ^x (700; 0.50)	700-900	28)	-	-	C_p by DSC, second max. (700; >0.80); ΔC_p indir., const. with T
	7.45 ^x (698; 0.50)	573-723	29)	-12320 ^x (723; 0.5)	29)	ΔC_p indir., const., second max (698; >0.8)
	5.5 ^x (1070; 0.35)	950-1250	30)	-11060 ^x (973; 0.5)	30)	ΔC_p indir. const.

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System	$\Delta C_p(T; x_i)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_i)$ (J mol ⁻¹)	Ref.	Remarks
Au-Te	0.55 (800; 0.33) 2.10 (737; 0.33)	737-873 700-1000 737-1200	19) 88) 89)	-500 κ (1000; 0.3) -1070 κ (737; 0.45)	88) 89)	C_p dir., const. ΔH^M neg. & pos. ΔC_p indir., decr. with T; ΔH^M neg. & pos.
Au-Tl	0	825-923	2)	-1170 κ (823; 0.65)	2)	ΔH^M const.
Ba-Mg	4.5 κ (1000; 0.3)	-	31)	-8330 κ (1050; 0.30)	32)	C_p by drop cal.
Bi-Ga	0.56 κ (700; ~0.5)	545-873	33)	+2060 κ (545; 0.45)	33)	ΔC_p indir., const.
Bi-In	-0.5 (600; 0.5)	383-750	34)	-1840 κ (900; 0.4)	16)	C_p direct for one comp., const.; C_p with C_p for In ^(L) by Grønbold(90); $\Delta C_p = 0$ or slightly pos.
Bi-Pb	0	623-723	35)	-1100 κ (623; 0.52)	35)	ΔH^M const.
Bi-Se	pos. (1000; 0.4)	1000-1100	36)	-22450 κ (998; 0.40)	37)	C_p by drop cal. for one comp.; sharp decr. of C_p within 20 K above liqu.; ΔH^M const. or very slight f(T)
Bi-Te	pos. (?) (860; 0.4)	860-923	38)	-10000 κ (877; 0.46)	39)	C_p by const. T-gradient cal. for one comp., sharp decr. of C_p within 30 K above liqu.
Ca-Mg	4.8 κ (1100; 0.5)	-	31)	-6280 κ (1150; 0.46)	40)	C_p by drop cal.
Cd-In	neg.	623-723	41, 42)	+1486 κ (623; 0.48)	42)	ΔH^M a slight f(T), decr. with T (41, 42)
Cd-Pb	0	623-723	35)	+2648 κ (623; 0.50)	35)	ΔH^M const.
Cd-Sb	4.78 κ (693; 0.57)	693-903	43)			C_p dir. by const. T-gradient cal.; ΔC_p decr. with T, $\Delta C_p \approx 0$ at~833 K
	2.34 κ (783; 0.5)	693-773	44)	-2520 κ (693; 0.55)	44)	ΔC_p indir., const. with T; ΔH^M pos & neg.
Cd-Sn	-1.5 (675; 0.5)	623-723	35)	+2028 κ (623; 0.60)	35)	ΔC_p indir., ΔC_p const.
Cd-Tl	neg.	623-723	42)	>+2369 κ (623; > 0.60)	42)	ΔH^M a slight f(T), by two different groups.

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System	$\Delta C_p(T; x_i)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_i)$ (J mol ⁻¹)	Ref.	Remarks
Ce-Cu	5.0 \times (1900; 0.33)	1650-2200	45)			C_p by levitation cal., const.
Cs-K	pos. (?)		46)	+117 \times (384; 0.4)	16)	ΔC_p changing with T, min. between 700-900 K.
Cs-Na	pos. (?)		46)	+1000 \times (384; 0.4)	16)	see Cs-K
~ 0		380-440	100)	+1096 \times (383; 0.4)	100)	
Cs-Sb	28.0(1000; 0.75)	1000-1130	47)	-95000 \times (1000; 0.75)	47)	C_p by dross cal. from $x_{Cs} = 0.75$ -1.00, linear, const.
Cu-Ga	6.30(1050; 0.55)	988-1107	2)	-12650 \times (1107; 0.70)	2)	ΔC_p indir., const.
Cu-In	11.31 \times (1125; 0.75)	903-1348	48)	-6766 \times (955; 0.75)	48)	ΔC_p indir., const.; ΔH^M pos. & neg.
Cu-Sb	8.9 \times (1070; 0.75)	960-1190	49)	-6920 \times (1003; 0.75)	49)	ΔC_p indir., second max 7.0 (1070 \pm 0.5) >1190 K; $\Delta C_p \approx 0$; ΔH^M pos. & neg.
Cu-Sn	3.76(1250; 0.80)	1123-1423	2)	-5925 \times (1113; 0.80)	2)	ΔC_p indir., const., ΔH^M by two differ. groups; ΔH^M neg. but tends to be pos. for Sn-rich comp.
9.2 \times (1073. 0.75)	-		50)	-		C_p by adiabatic cal.
Cu-Te	16.54(870; 0.44)	727-1005	91)	-15300(727; 0.44)	91)	ΔC_p indir., const., standard state
Cu-Ti	42.6(700; 0.60)	700-1600	51)	-3731 \times (1372; 0.50)	52)	ΔC_p calc., $\Delta C_p = 41.0$ (1600 K)
Ga-Hg	pos.(475; 0.50 ₃)	475-483	53)	+1800 \times (478; 0.55)	54)	C_p dir. by pulse modulation technique for one comp., ΔC_p pos. for ~ 5 K above T_c
Ga-In	0	423-742	55)	+1110 \times (423; 0.50)	55)	ΔH^M const.
Ga-Mg	3(972; 0.286)	-	56)	-11500 \times (972; 0.45)	56)	C_p by cal. for one comp.
Ga-Te	60 \times (1120; 0.4)	liqu-1173	101)	-38800 \times (1200; 0.39)	58) 11) 101)	ΔH^M const. (1123-1200 K) C_p direct by adiabatic cal. for 5 comp. $x_{Ga} = 0.30, 0.60, 0.67, C_p$ decr. slightly with T; $x_{Ga} = 0.40, 0.50$, first incr. with T, then decr.

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Ge-Pt	6.3(1300; 0.60)	1273-1352	59)	-52000*(1273; 0.42)	59)	ΔC_p indir., const.
Ge-Te	19.3(1080; 0.50)	1030-1150	60)	-14800(1028; 0.46)	60)	ΔC_p indir.
	13.4(990; 0.50)	990-1300	57)	-		C_p by drop cal. for one comp. ΔC_p decr. with T to 4.1 (1300 K)
pos.	663-743	61)				C_p by DSC for one comp. ($x_{Te} = 0.15$) ; between 663 and 743 K C_p drops drastic.
Hg-Na	12.85*(633; ~0.70)	-	62)	-17450*(648; 0.60)	16)	ΔC_p indir., derived
	10.0*(628; ~0.80) liqu.-673	92)	-			ΔC_p indir.; derived, $\Delta C_p(\text{min}) = -2.5$ ($x_{Hg} \approx 0.5$)
Hg-Tl	pos.	288-533	63)	-816*(383; 0.60)	63)	ΔC_p indir.; ΔH^M tends to be pos. for Tl-rich comp., $\Delta C_p(Tl)$ pos., decr. with T (64)
In-Na	6.44*(750; 0.65)	liqu.-773	93)	-9177*(723; 0.55)	93)	ΔC_p and ΔH^M indir. by emf.
In-Sb	2.5(923; 0.50)	-	65)	-3500*(923; 0.55)	65)	ΔC_p indir.
	4.3*(971; 0.70)	971-1158	66)	-3210*(957; 0.60)	66)	ΔC_p indir., max. +3.6 (1158; 0.60)
pos.		67)	-			C_p by drop cal. for one comp. ($x_{In} = 0.5$), C_p max. at ~850 K (~50 K above m.p.)
In-Sn	0	394-758	68)	-197*(700; 0.50)	16)	C_p dir. for one comp. ($x_{In} = 0.528$), decr. with T
In-Te	37.2*(1050; 0.40)	737-1340	69)	-36500*(987; 0.45)	69)	ΔC_p indir., $\Delta C_p = 0$ ($T < 1000$ K), $\Delta C_p =$ 37.2(987-1P23), $\Delta C_p = 18.20(1123-1340$ K)
	54.5*(1023; 0.40)	948-1123	70)	-34000*(998; 0.40)	71)	C_p direct by adiabatic cal., ΔC_p first slightly incr. then decr. with T.
K-Na	1.59(305; 0.33)	305-320	72)	+737*(384; 0.60)	16)	C_p direct for one comp. ΔC_p decr. with T, $\Delta C_p = 1.22(320$ K); see also Cs-K (46)
Li-Mg	8.4*(800; 0.50)	800-900	73)	-3300*(940; 0.50)	94)	C_p by DSC, ΔC_p const.
Li-Pb	pos. (?)	800-900	74)	-29530*(1000; ~0.75)	75)	ΔC_p (Li) pos.
Mg-Pb	5.0*(1100; ~0.65)	943-1233	76)	-9600*(943; 0.64)	76)	ΔC_p indir., const.

System	$\Delta C_p(T; x_i)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_i)$ (J mol ⁻¹)	Ref. Remarks
Mg-Sn	10.4*(1150; ~0.65)	1073-1213	76)	-14800*(1073; 0.64)	76) ΔC_p indir., const.
Mg-Sr	4.0*(1000; ~0.70)	-	31)	-5520*(1080; 0.65)	32) C_p by drop cal., ΔC_p const.
Na-Pb	12.5*(698; 0.76)	698-803	102)	-17900*(698; 0.60)	102) ΔC_p and ΔH^M indir. by emf; second max ΔC_p appears by extrapolation at $x_{Na} = 0.57$ at 648 K ; ΔC_p decr. with T
Na-Sn	4.64*(810; 0.25)	liqu. -856	93)	-20737(773; 0.54)	93) ΔC_p and ΔH^M indir. by emf; second max $\Delta C_p = 4.24$ ($x_{Na} = 0.44$) ; ΔC_p neg ($x_{Na} < 0.041$)
	21.0*(873; ~0.5)	liqu. -873	95)	-20080(873; 0.55)	95) ΔC_p and ΔH^M indir. by emf; second max $\Delta C_p = 12.5$ ($x_{Na} = 0.75$) ; ΔC_p incr. with T (?)
Na-Tl	4.2*(673; ~0.50)	593-893	77)	-11700*(753; 0.50)	78) ΔC_p indir., const.
Ni-Sn	27*(1623; 0.75)	1623-1723	79)	-19500*(1773; 0.60)	16) ΔC_p indir., $\Delta C_p = 27.0$ (1723; 0.60)
Pb-Sn	0	623-723	80)	+1390*(623; 0.50)	80) ΔH^M const.
Pd-Si	60(?)* (1600; 0.63)	1380-1838	81)	-87000*(1380; 0.63)	81) ΔC_p indir., const.; ΔH^M by two groups; $\Delta H^M = -56000$ (1838; 0.63) (82)
				-74900*(1723; 0.665)	98) ΔC_p (Pd) pos. indir., $\Delta \bar{C}_p^\infty$ (Pd) pos.
Pd-Sn	pos. (?)	700-800	83)		
S-Tl	~0	631-753	84)	-79400*(753; 0.33)	84) ΔH^M const.
Sb-Se	pos. (900; 0.40)	900-1100	36)	-29400*(935; 0.40)	37) C_p by drop cal. for one comp., sharp decr. of C_p within ~ 25 K above liqu.; ΔH^M very slight f(T)
Sb-Sn	0.5*(930; ~0.50)	783-1108	85)	-1390*(905; 0.50)	16) ΔC_p indir., const.
Sb-Zn	14.00*(828; ~0.45)	828-918	86)	-3310*(823; 0.45)	86) ΔC_p indir., dec H^M . with T, $\Delta C_p \approx 0$ at 1010 K ; ΔH^M neg. and pos.

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System	$\Delta C_p(T; x_i)$ (J K ⁻¹ mol ⁻¹)	T-range (K)	Ref.	$\Delta H^M(T; x_i)$ (J mol ⁻¹)	Ref. Remarks
Se-T1	~0	631-753	84)	-93300*(753; 0.33)	84) ΔH^M const.
	23.2*(700; 0.40)	655-738	96)	-32600(675; 0.333)	96) ΔC_p indir. by cal.
	10.92(672; 0.333)	672-825	97)	-	C _p by drop cal. for two comp.; at $x_{Se} = 0.333 \Delta C_p$ decreases with T to 3.05 at 835 K
Sn-Zn	~0	925	65)	+3350*(923; 0.4)	65) ΔC_p indir.
	-3*(750; 0.50)	703-798	35)	+3412*(703; 0.44)	35) ΔC_p indir., const.
Te-T1	4.5*(830; 0.33)	740-1123	99)	-28100*(917; 0.33)	99) ΔC_p indir., incr. slightly with T, $\Delta C_p = 6.7$ (1070; 0.33), ΔC_p should decr. at still higher T

Footnote : Numbers marked with an asterisk(*) are extreme values (maxima or minima) of ΔC_p or ΔH^M in the system.
In parentheses are temperature in K and mole fraction x_i . The mole fraction is that of the element listed first in alphabetical order.

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above T_c . Of the 12 systems with $\Delta C_p = 0$ ΔH^M is positive for six, weakly negative for three, and strongly negative for three. Of the four systems with a - relatively small - negative ΔC_p three have a positive ΔH^M and one (Bi-In) a negative. However, when ΔC_p for the latter system is calculated using the adiabatically determined C_p for indium, ΔC_p is either zero or slightly positive.

For all systems where C_p has been measured directly (Ag-Ge, Au-Ge, Au-In, Au-Si, Au-Sn, Cd-Sb, Ge-Te, In-Te), and therefore presumably with higher precision, ΔC_p decreases with increasing temperature and seems to approach $\Delta C_p = 0$. Exceptions seem to be the adiabatically determined constant ΔC_p values for Au-Ga, Au-In, Au-Sb, Au-Sn, Au-Te and Cu-Sn by one group of authors (Itagaki and co-workers) but they found a constant ΔC_p for Au-In and Au-Sn where DSC measurements (Janitsch, Komarek, Mikler) have definitely established that ΔC_p decreases with increasing temperature. In the In-Te system ΔC_p for $In_2Te_3(L)$ seems to first increase slightly then to decrease with increasing temperature. In the Au-Sn system ΔC_p seems to become negative at very high temperature (Hayer et al.) but this observation again is based on indirect measurements. In the In-Te system measurements of ΔH^M (Said, Castanet) have indicated that $\Delta C_p = 0$ for $T < 1000$ K, and ΔC_p positive for $T > 1000$ K decreasing with temperature but again the evidence is indirect. Although the data in general are still too sketchy and in many cases too unreliable some generalizations can be made. As pointed out previously (18) chemical short range order (association of unlike atoms) can be expected to occur in about 300 out of 435 liquid binary systems of main group (plus IB and IIB) elements, therefore some deviations from metallic bonding will be the rule and not the exception. A comparison shows that all systems with positive ΔC_p belong to the 300 systems with chemical short range order (CSRO), and it is safe to assume that more of these systems will show a positive ΔC_p although in cases with strong CSRO ΔC_p - at least over a limited temperature range - can also be zero (e.g. Ag-Te, partly Ga-Te). The magnitude of ΔC_p^* (maximum value) for systems with CSRO can cover a wide range from 54 J $K^{-1} mol^{-1}$ for In-Te to about 4 J $K^{-1} mol^{-1}$ for Au-Ge but for most system ΔC_p^* close to the liquidus temperature seems to fall into the range from 5 to 10 J $K^{-1} mol^{-1}$. The temperature range over which ΔC_p decreases to zero also varies between 150 to 200 K (Ag-Ge, Cd-Sb) and about 500 K (Au-Si, Au-Sn). There are indications that ΔC_p might even become slightly negative at higher temperatures (Ag-Ge, Au-Si, Au-Sn) but more experimental confirmation is needed. There is apparently no relationship between the magnitudes of (negative) ΔH^M and ΔC_p^* small : ΔH^M - values can be associated both with large ΔC_p^* (e.g. Ag-Ge) and small ΔC_p^* (e.g. Cd-Sb) as can be large ΔH^M - values (small ΔC_p^* in Au-In and Au-Sn, large ΔC_p^* in In-Te). When ΔH^M is positive ΔC_p is either zero or possibly slightly negative but evidence for this is scarce and indirect. Just above a miscibility gap ΔC_p is also positive (Ga-Hg) but it decreases much faster with increasing temperature towards zero (or negative values ?) than in systems with CSRO. Density fluctuations (clusters) between like atoms are much less stable than interactions between unlike atoms as a comparison of the system Ga-Hg and Cd-Sb shows.

Conclusion

The relative heat capacity of a liquid alloy, the (positive) deviation from Neumann-Kopp rule is therefore in many instances an important indicator of CSRO as has been previously realized for associations in liquid organic binary systems (19). The physical interpretation of CSRO and consequently of ΔC_p is another matter. The volume change on mixing due to the size difference of the pure component atoms will possibly be a contributing factor but it cannot explain the entire deviation or else it would have a larger effect on ΔC_p of systems with a positive ΔH^M . Presently the most plausible interpretation of CSRO are interactions or non-random associations between unlike atoms decreasing with increasing temperature as pointed out previously (15, 17). This leaves unanswered the questions of life time of the associations and of the type of interaction (covalent or ionic) but it can be explained by a temperature dependent chemical equilibrium between actual or hypothetical species. Such a reaction can be for example the dissociation of associated unlike atoms (associates), the randomization of ionic groupings, a temperature dependent charge-transfer (especially in transition metal alloys) or an equilibrium between differently charged ions. Thermodynamic quantities, especially ΔC_p , will not be able to settle these questions but they are very sensitive indicators of CSRO.

As far as ΔC_p is concerned much more experimental work of higher precision and reliability is required - a still largely untouched field for interested experimental thermodynamicists and thermochemists.

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